

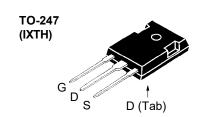
### X4-Class **Power MOSFET**

### IXTH120N20X4

N-Channel Enhancement Mode Avalanche Rated



$V_{\rm DSS}$	=	200V
   <sub>D25</sub>	=	120A
R <sub>DS(on)</sub>	≤	$9.5$ m $\Omega$



G = Gate	D	= Drain
S = Source	Tab	= Drain

Symbol	Test Conditions	Maximum Ra	atings
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 175°C	200	V
$\mathbf{V}_{DGR}$	$T_J$ = 25°C to 175°C, $R_{GS}$ = 1M $\Omega$	200	V
V <sub>GSS</sub>	Continuous	±20	V
V <sub>GSM</sub>	Transient	±30	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	120	A
I <sub>DM</sub>	$T_{\rm c}$ = 25°C, Pulse Width Limited by $T_{\rm JM}$	240	Α
I <sub>A</sub>	T <sub>C</sub> = 25°C	60	A
E <sub>as</sub>	T <sub>C</sub> = 25°C	1	J
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	20	V/ns
P <sub>D</sub>	T <sub>c</sub> = 25°C	417	W
T <sub>J</sub>		-55 +175	°C
T <sub>JM</sub>		175	°C
T <sub>stg</sub>		-55 +175	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C
-	1.6 mm (0.062 in.) from Case for 10s		
M <sub>d</sub>	Mounting Torque	1.13 / 10	Nm/lb.in
Weight		6	g

#### **Features**

- International Standard Package
- Low R<sub>DS(ON)</sub> and Q<sub>G</sub>
   Avalanche Rated
- Low Package Inductance

#### **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

#### **Applications**

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

<b>Symbol Test Conditions</b> (T <sub>J</sub> = 25°C, Unless Otherwise Specified)		Characteristic Values Min.   Typ.   Max.			
BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	200			V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.5		4.5	V
I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			25 500	μ <b>Α</b> μ <b>Α</b>
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$			9.5	mΩ

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Symbol	Test Conditions		acteristic	
$(T_J = 25^{\circ}C, L)$	Inless Otherwise Specified)	Min.	Тур.	Max
$\mathbf{g}_{fs}$	$V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$	72	120	S
$R_{Gi}$	Gate Input Resistance		6	Ω
C <sub>iss</sub>			6100	pF
c <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		865	pF
C <sub>rss</sub>			1.8	pF
	Effective Output Capacitance			
C <sub>o(er)</sub>	Energy related $\bigvee_{GS} = 0V$		510	pF
C <sub>o(tr)</sub>	Time related $\int_{0.8}^{0.8} V_{DS} = 0.8 \cdot V_{DSS}$		2000	pF
t <sub>d(on)</sub>	Resistive Switching Times		13	ns
t <sub>r</sub>	<del>-</del>		24	ns
t <sub>d(off)</sub>	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_{D} = 0.5 \cdot I_{D25}$ $R_{G} = 2\Omega$ (External)		100	ns
t,	N <sub>G</sub> – 232 (External)		12	ns
Q <sub>g(on)</sub>			108	nC
Q <sub>gs</sub>	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		27	nC
$\mathbf{Q}_{gd}^{gd}$			27	nC
R <sub>thJC</sub>				0.36 °C/W
R <sub>thcs</sub>			0.21	°C/W

#### **Source-Drain Diode**

Symbol	Test Conditions	Chara	cteristic	Values	
$(T_{J} = 25^{\circ}C, U)$	Inless Otherwise Specified)	Min.	Тур.	Max	
I <sub>s</sub>	$V_{GS} = 0V$			120	Α
I <sub>SM</sub>	Repetitive, pulse Width Limited by $T_{_{JM}}$			480	Α
V <sub>SD</sub>	$I_F = 100A, V_{GS} = 0V, Note 1$			1.4	V
$\left. egin{array}{l} \mathbf{t}_{rr} & \ \mathbf{Q}_{RM} & \ \mathbf{I}_{RM} & \end{array}  ight.  ight.$	$I_F = 60A$ , -di/dt = 200A/ $\mu$ s $V_R = 100V$		190 3.2 33.7		ns µC A

Note 1. Pulse test,  $t \le 300 \mu s$ , duty cycle,  $d \le 2\%$ .

# IXTH120N20X4

Fig. 1. Output Characteristics @  $T_J = 25$ °C

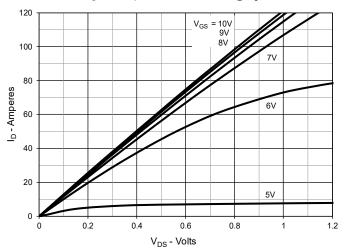


Fig. 2. Extended Output Characteristics @ T<sub>J</sub> = 25°C

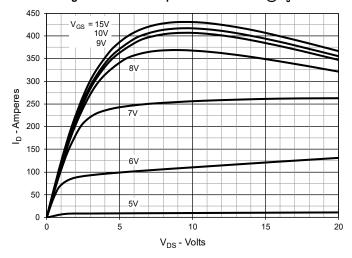


Fig. 3. Output Characteristics @  $T_J = 150$  °C

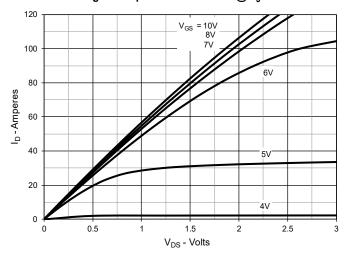


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D$  = 60A Value vs. Junction Temperature

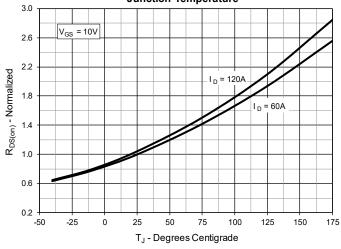


Fig. 5. R<sub>DS(on)</sub> Normalized to I<sub>D</sub> = 60A Value vs.

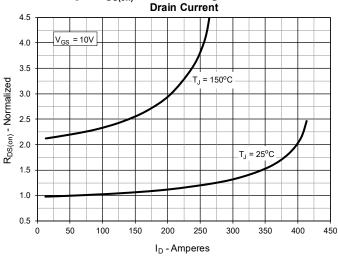
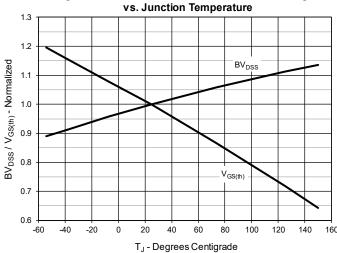
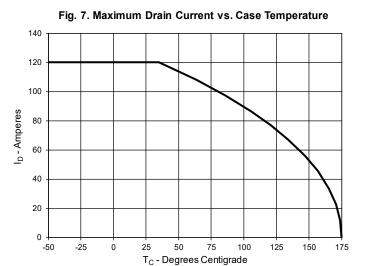


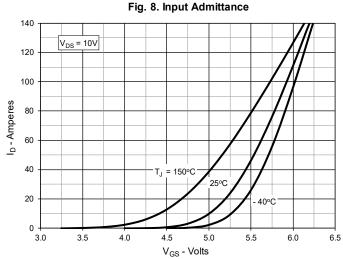
Fig. 6. Normalized Breakdown & Threshold Voltages

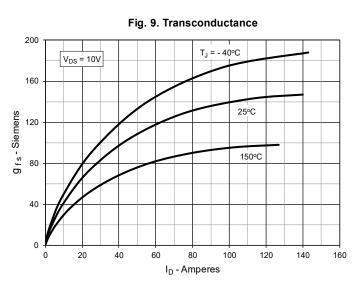


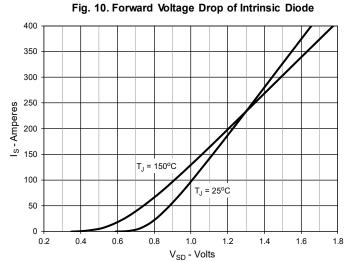
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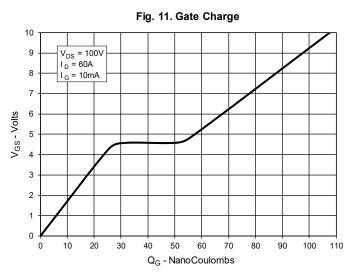


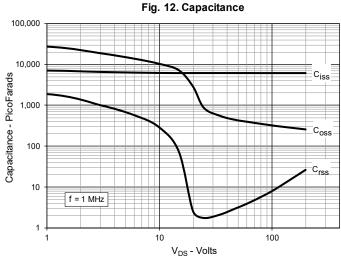






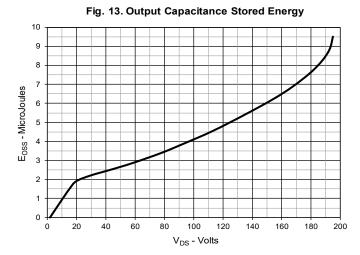






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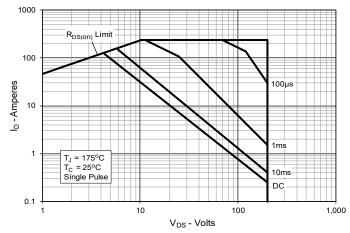
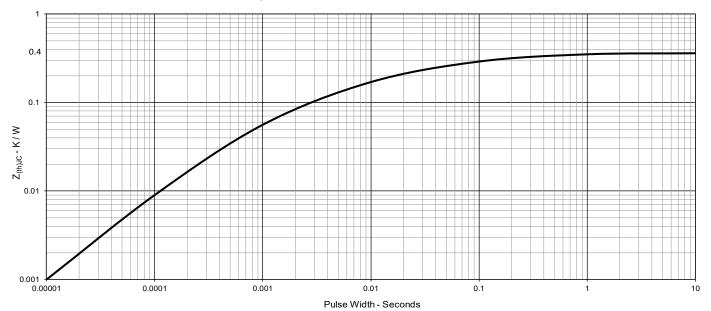
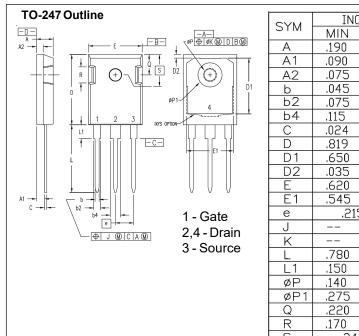


Fig. 15. Maximum Transient Thermal Impedance



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SYM	INCHES		MILLIMETERS		
2 1 IVI	MIN	MAX	MIN	MAX	
Α	.190	.205	4.83	5.21	
Α1	.090	.100	2.29	2.54	
A2	.075	.085	1.91	2.16	
b b2	.045	.055	1.14	1.40	
b2	.075	.087	1.91	2.20	
b4	.115	.126	2.92	3.20	
O	.024	.031	0.61	0.80	
D	.819	.840	20.80	21.34	
D1	.650	.690	16.51	17.53	
D2	.035	.050 _	0.89	1.27	
E	.620	.635	15.75	16.13	
E1	.545	.565	13.84	14.35	
ω	.215	BSC	5.45	BSC	
7	I	.010	ļ	0.25	
Κ		.025		0.64	
	.780	.810	19,81	20.57	
L1	.150	.170	3.81	4.32	
φP	.140	.144	3,55	3.65	
øP1	.275	.290	6.99	7.37	
Q	.220	.244	5,59	6.20	
R	.170	.190	4.32	4.83	
S	.242	BSC	6.15 BSC		



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